



LITE-ON TECHNOLOGY CORPORATION

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LED DISPLAY

LTS-4817SW-P DATA SHEET

<u>ITEM</u>	<u>Description</u>	<u>By</u>	<u>DATE</u>
1	New Spec	Reo Lin	2011/08/24

FEATURES

- * 0.39 inch (10.0 mm) DIGIT HEIGHT
- * CONTINUOUS UNIFORM SEGMENTS
- * LOW POWER REQUIREMENT
- * EXCELLENT CHARACTERS APPEARANCE
- * HIGH BRIGHTNESS & HIGH CONTRAST
- * WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY
- * CATEGORIZED FOR LUMINOUS INTENSITY
- * SMD DISPLAY
- * **LEAD FREE PACKAGE (ACCORDING TO ROHS)**

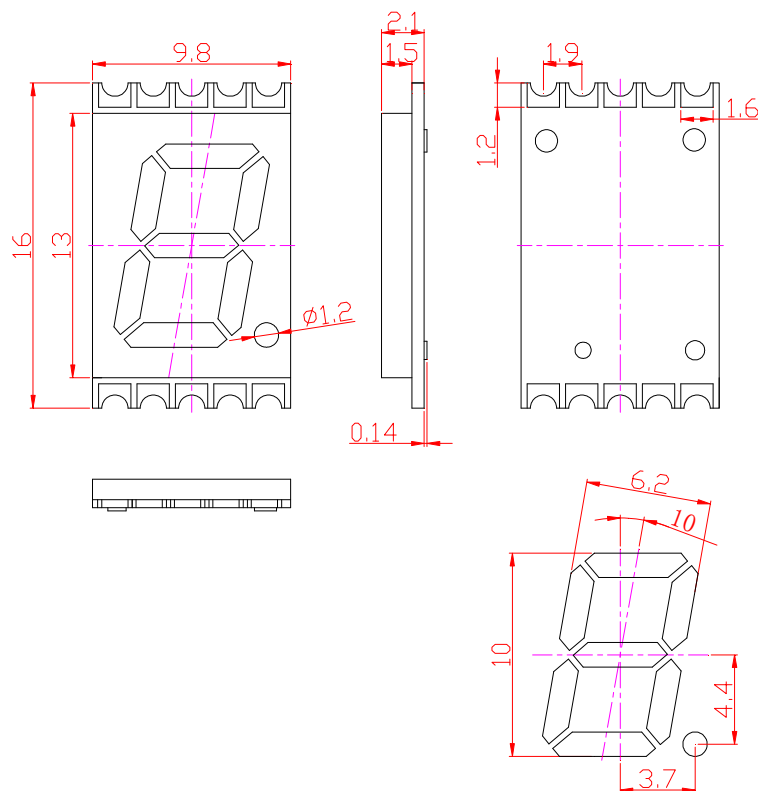
DESCRIPTION

The LTS-4817SW-P is a 0.39 inch (10.0 mm) digit height single digit SMD display. This device uses LTW-C193 series InGaN white Chip LED. The display has gray face and white segments, and suitable for reverse mount assembly.

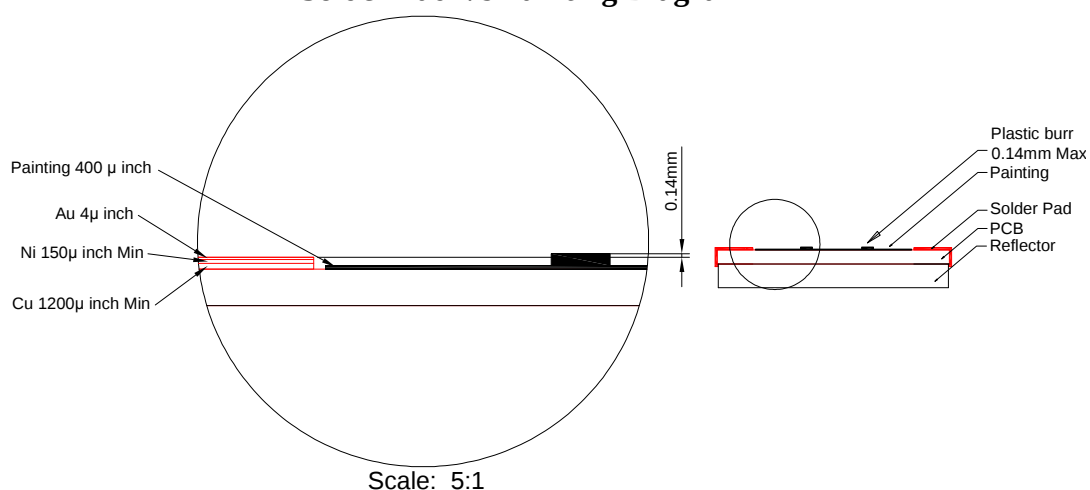
DEVICE

PART NO.	DESCRIPTION
InGaN White	Common Anode
LTS-4817SW-P	

PACKAGE DIMENSIONS



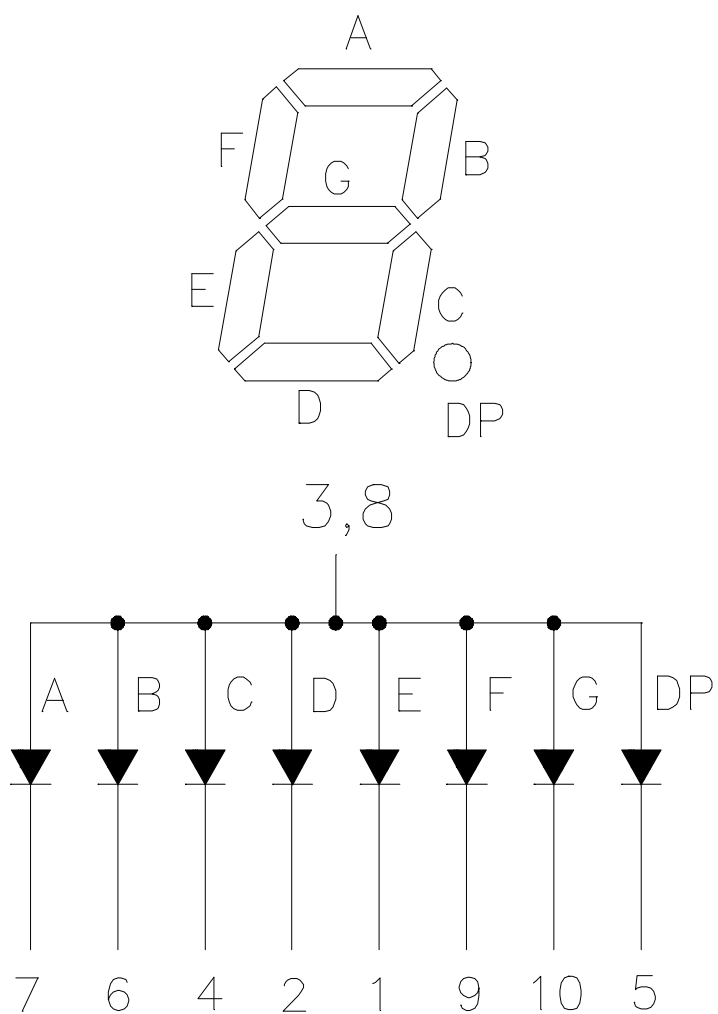
Solder Pad Vs Painting Diagram



NOTES:

1. Plastic pins' burr max. 0.14 mm,
2. All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.
3. Solder pad materials and thickness: Cu: 1200 μ inch Ni: Min 150 μ inch Au: 4 μ inch.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No.	CONNECTION
1	CATHODE E
2	CATHODE D
3	COMMON ANODE
4	CATHODE C
5	CATHODE D.P.
6	CATHODE B
7	CATHODE A
8	COMMON ANODE
9	CATHODE F
10	CATHODE G

ABSOLUTE MAXIMUM RATING AT Ta = 25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment (Frequency 1Khz,10% duty cycle)	100	mA
Continuous Forward Current Per Segment	20	mA
Forward Current Derating from 25 °C	0.25	mA/°C
Operating Temperature Range	-35 °C to +80 °C	
Storage Temperature Range	-55 °C to +105 °C	
Iron Soldering Conditions: 1/16 inch Below Seating Plane for 3 Seconds at 260 °C		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta = 25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Luminous Intensity	IV	28.0	44.0		mcd	IF = 5mA Note 1, 2, 5
Chromaticity Coordinates	x		0.294			IF = 5mA Note 3, 5
	y		0.286			
Forward Voltage Per Segment	V _F	2.70		3.2	V	IF = 5mA
Reverse Current Per Segment	I _R			100	μA	V _R =5V Note 7

Note:

1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.
2. Iv classification code is marked on each packing bag.
3. The chromaticity coordinates (x, y) is derived from the 1931 CIE chromaticity diagram.
4. Caution in ESD:
Static Electricity and surge damages the LED. It is recommend using a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.
5. Tester: CAS140B is for the chromaticity coordinates (x, y) and IV.
6. The chromaticity coordinates (x, y) guarantee should be added ± 0.01 tolerance.
7. Reverse voltage is only for IR test. It can not continue to operate at this situation.

Chip LED Bin Code List

V_F Spec. Table		
V _F Bin	Forward Voltage (V) at I _F =5mA	
	Min.	Max
3	2.7	2.8
4	2.8	2.9
5	2.9	3.0
6	3.0	3.1
7	3.1	3.2

Tolerance on each Forward Voltage bin is +/-0.1 volt

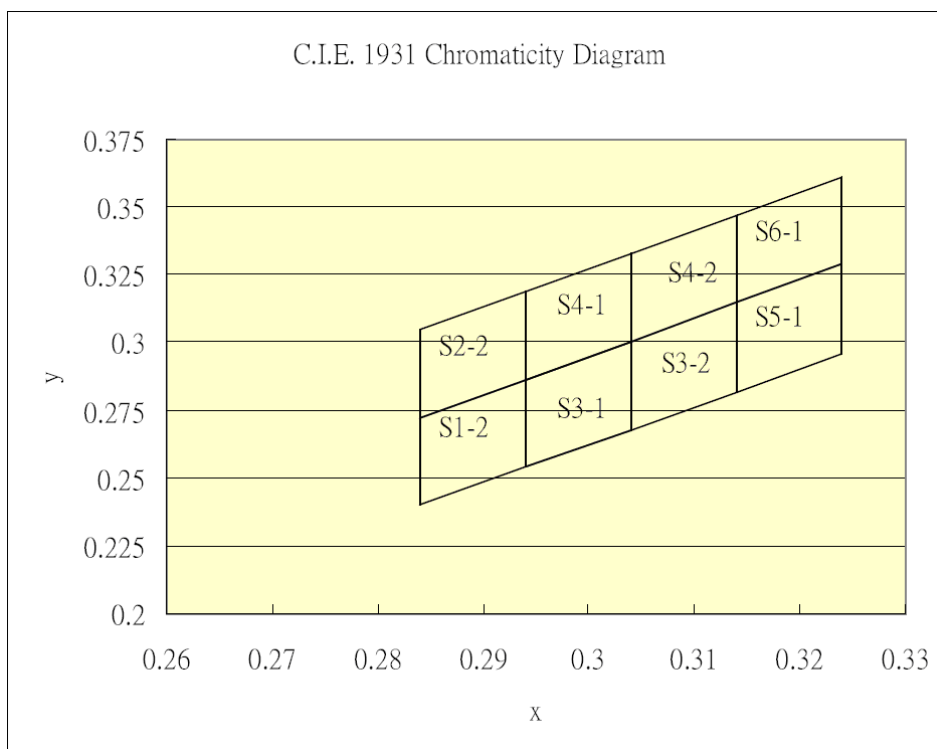
I_v Spec. Table		
I _v Bin	I _v (mcd) at I _F =5mA	
	Min.	Max.
Q11	71.0	81.0
Q12	81.0	90.0
Q21	90.0	101.0
Q22	101.0	112.0
R11	112.0	129.0
R12	129.0	146.0
R21	146.0	165.0

Tolerance on each Luminous Intensity bin is +/-10%

Color Ranks Table					
Ranks	Color bin limits at I _F =5mA				
	CIE 1931 Chromaticity coordinates				
S1-2	x	0.284	0.284	0.294	0.294
	y	0.240	0.272	0.286	0.254
S2-2	x	0.284	0.284	0.294	0.294
	y	0.272	0.305	0.319	0.286
S3-1	x	0.294	0.294	0.304	0.304
	y	0.254	0.286	0.300	0.268

S3-2	x	0.304	0.304	0.314	0.314
	y	0.268	0.300	0.315	0.282
S4-1	x	0.294	0.294	0.304	0.304
	y	0.286	0.319	0.333	0.300
S4-2	x	0.304	0.304	0.314	0.314
	y	0.300	0.333	0.347	0.315
S5-1	x	0.314	0.314	0.324	0.324
	y	0.282	0.315	0.329	0.296
S6-1	x	0.314	0.314	0.324	0.324
	y	0.315	0.347	0.361	0.329

Tolerance on each Hue (x,y) bin is +/- 0.01



TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

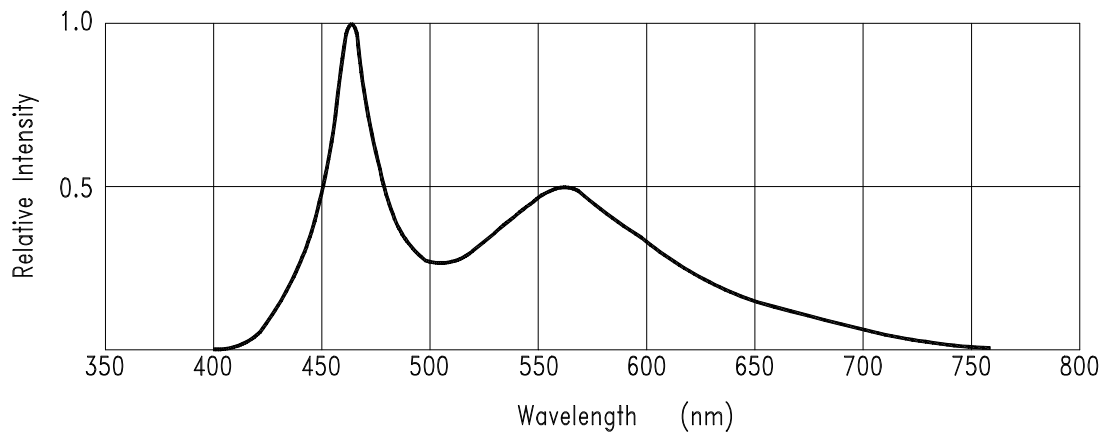


Fig.1 RELATIVE INTENSITY VS. WAVELENGTH

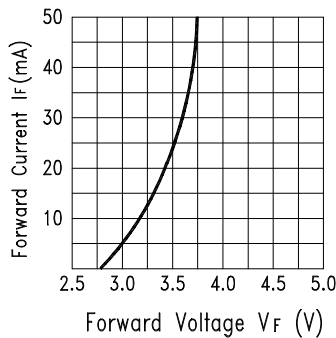


Fig.2 Forward Current vs.
Forward Voltage

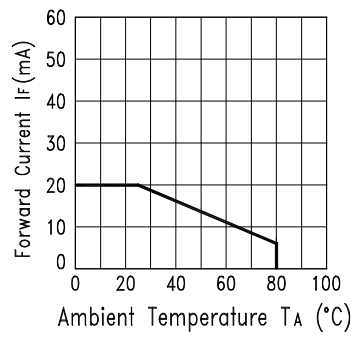


Fig.3 Forward Current
Derating Curve

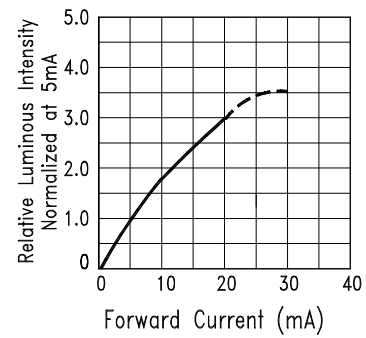


Fig.4 Relative Luminous Intensity
vs. Forward Current

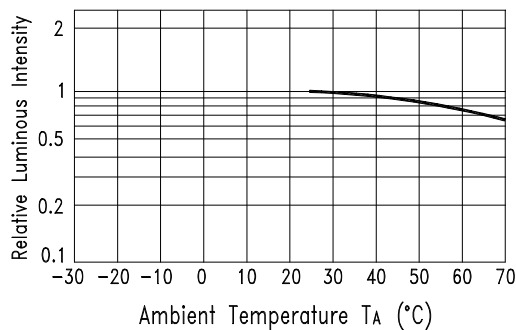


Fig.5 Luminous Intensity vs.
Ambient Temperature

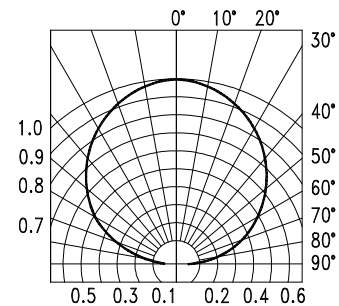
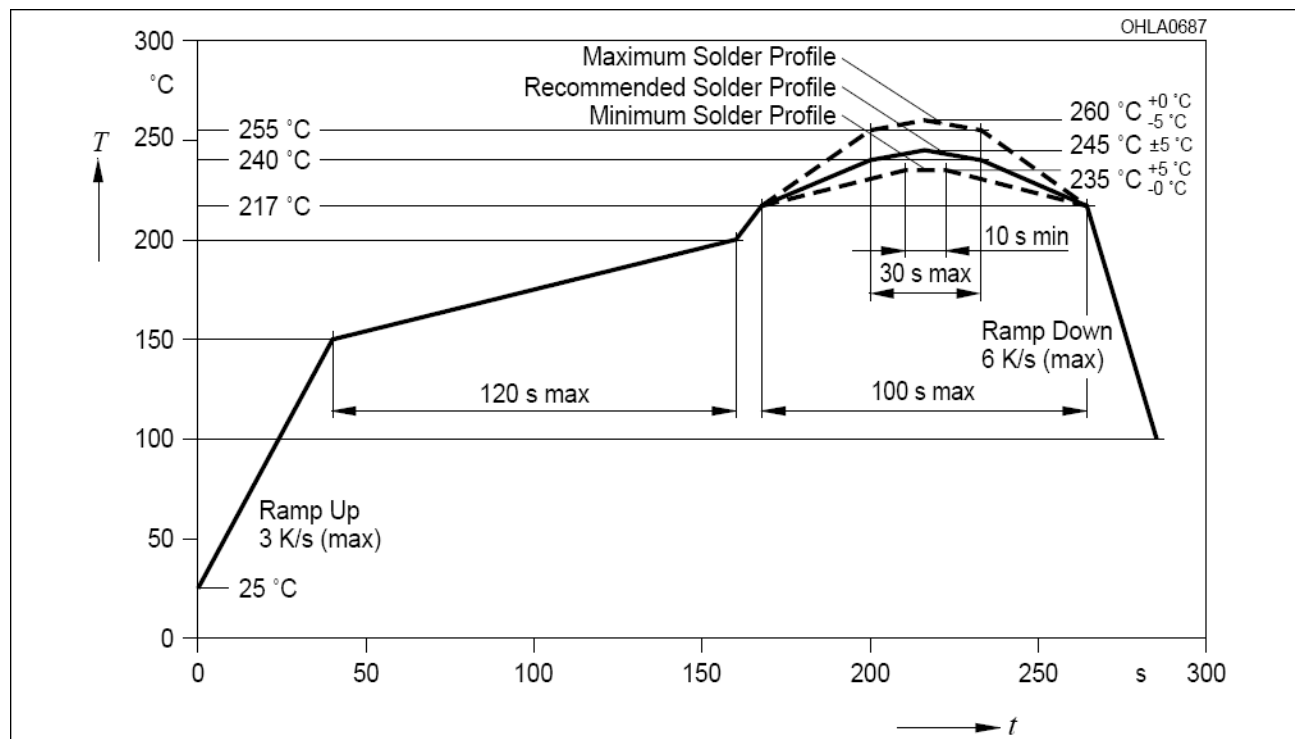


Fig.6 Spatial Distribution

SMT SOLDERING INSTRUCTION

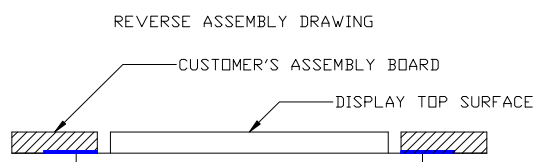
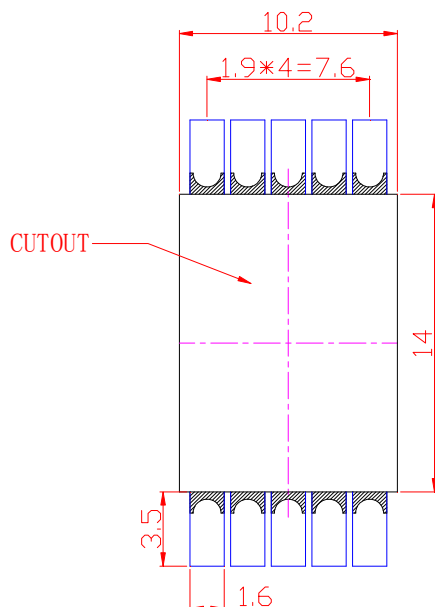


Note:

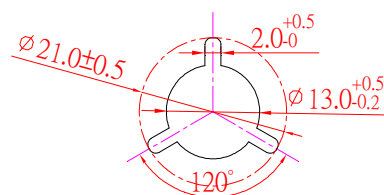
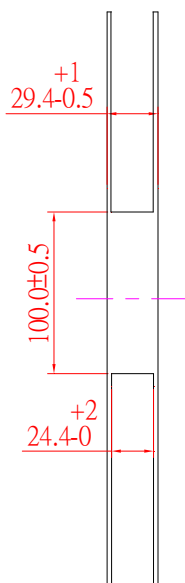
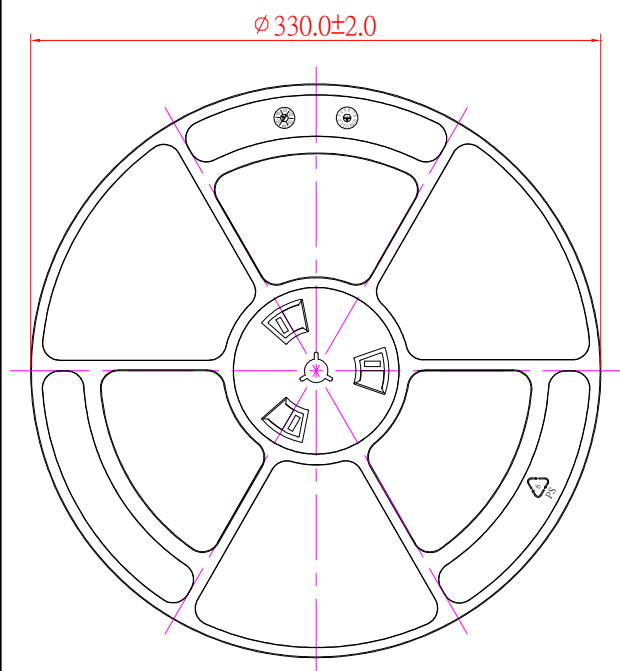
1. Recommended soldering condition:

Reflow Soldering (Two times only)		Soldering Iron (One time only)	
Pre-heat:	120~150°C.	Temperature	300°C Max.
Pre-heat time:	120sec. Max.	Soldering time	3sec. Max.
Peak temperature:	260°C Max.		
Soldering time:	5sec. Max.		

2. Number of reflow process shall be less than 2 times, and cooling process to normal temperature is required between the first and the second soldering process.

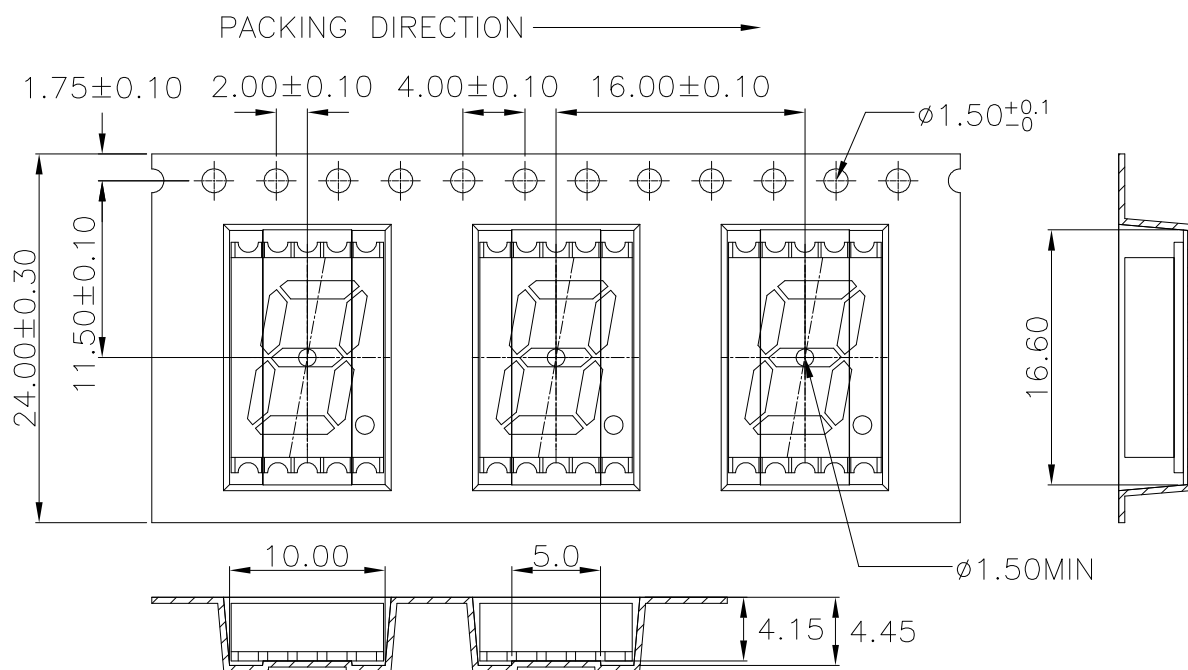
RECOMMENDED SOLDERING PATTERN


Note: All dimensions are in millimeters.

PACKING REEL DIMENSIONS


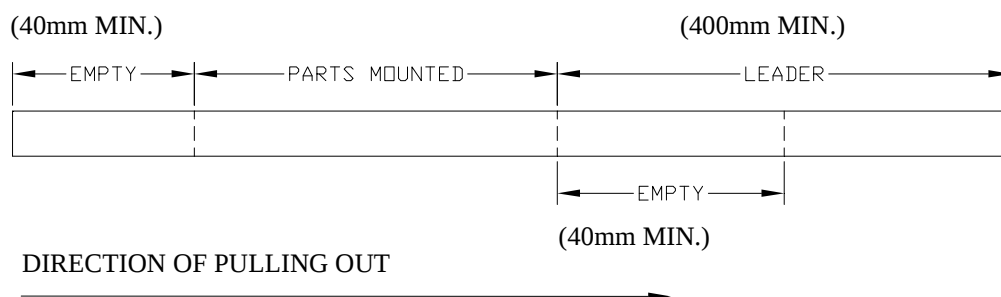
PACKING CARRIER DIMENSIONS

1. Taping parts:



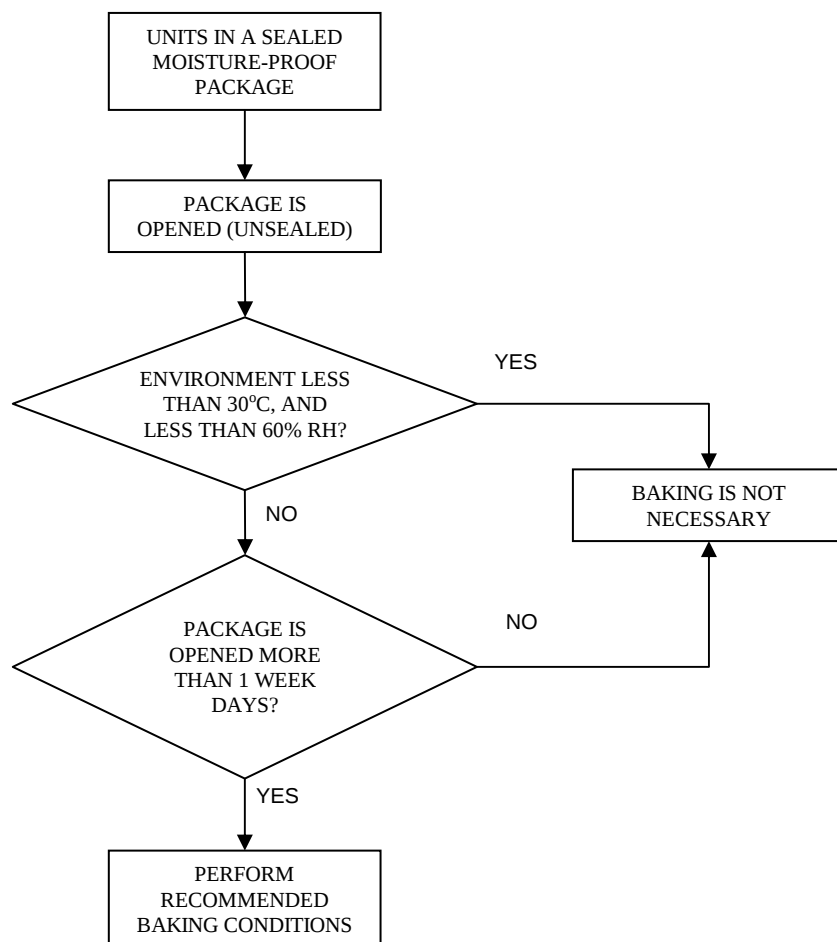
10 sprocket hole pitch cumulative tolerance ± 0.20 .
Carrier camber is within 1 mm in 250 mm.
Thickness : 0.40 ± 0.05 mm.
All dimensions meet EIA-481-C requirements.

2. Trailer part/ Leader part:



Moisture Proof Packaging

All N/D SMD displays are shipped in moisture proof package. The displays should be stored at 30°C or less and 90% RH or less. Once the package opened, moisture absorption begins.



Baking Conditions

If the parts are not stored in dry conditions, they must be baked before reflow to prevent damage to the parts.

Package	Temperature	Time
In Reel	60°C	≥ 48hours
In Bulk	100°C	≥ 4hours
	125°C	≥ 2hours

Baking should only be done once.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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